

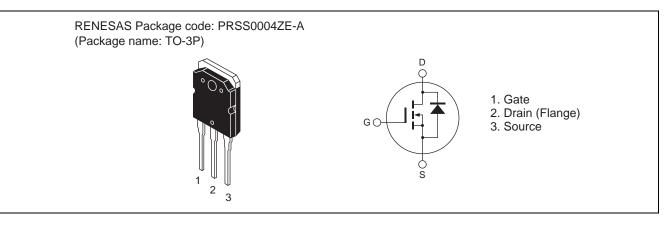
RJK5020DPK

Silicon N Channel MOS FET High Speed Power Switching

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	ID	40	А
Drain peak current	Note1 I _{D (pulse)}	120	А
Body-drain diode reverse drain current	I _{DR}	40	А
Body-drain diode reverse drain peak current	Note1 I _{DR (pulse)}	120	А
Avalanche current	I _{AP} ^{Note3}	12.5	А
Avalanche energy	E _{AR} ^{Note3}	8.6	mJ
Channel dissipation	Pch Note2	200	W
Channel to case thermal impedance	θch-c	0.625	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	٥C
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Notes: 1. $PW \leq 10~\mu s,~duty~cycle \leq 1\%$

2. Value at $Tc = 25^{\circ}C$

3. STch = 25° C, Tch $\leq 150^{\circ}$ C



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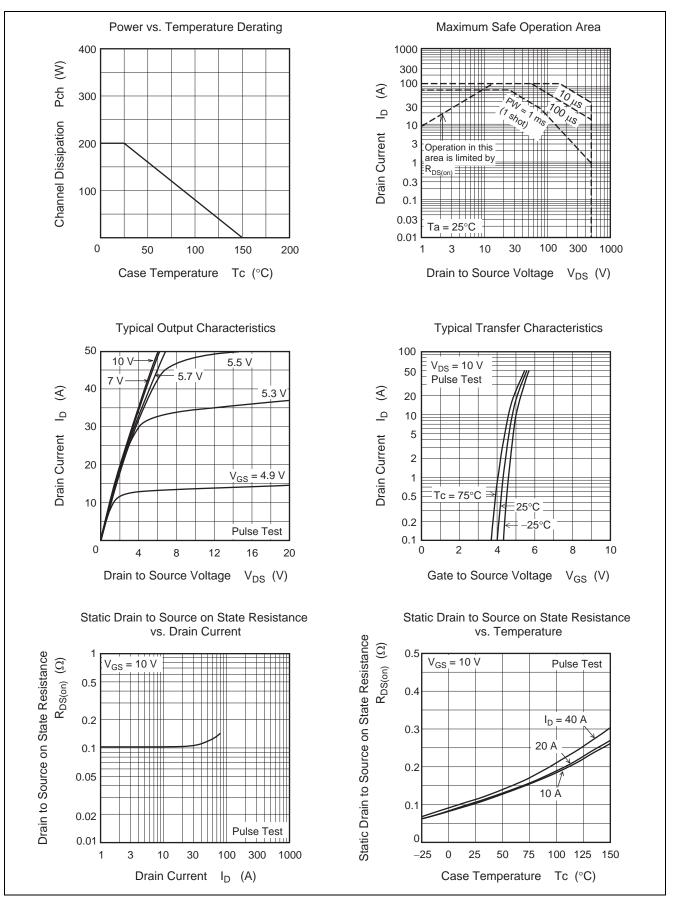
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	500	_	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	—	—	1	μΑ	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	—	0.102	0.118	Ω	$I_D = 20 \text{ A}, \text{ V}_{GS} = 10 \text{ V}^{Note4}$
resistance	Ciaa		5450		- 5	<u>)</u>
Input capacitance	Ciss		5150		pF	$V_{DS} = 25 V$
Output capacitance	Coss	_	525	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		55	—	pF	
Turn-on delay time	t _{d(on)}		52	—	ns	I _D = 20 A
Rise time	tr	_	115	—	ns	$V_{GS} = 10 V$ $R_L = 12.5 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	—	180	—	ns	
Fall time	t _f	—	125	—	ns	
Total gate charge	Qg	_	126	—	nC	V _{DD} = 400 V
Gate to source charge	Qgs	—	26	—	nC	V _{GS} = 10 V I _D = 40 A
Gate to drain charge	Qgd	_	54	—	nC	
Body-drain diode forward voltage	V _{DF}	_	0.90	1.50	V	$I_F = 40 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t _{rr}	—	450	—	ns	$I_F = 40 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

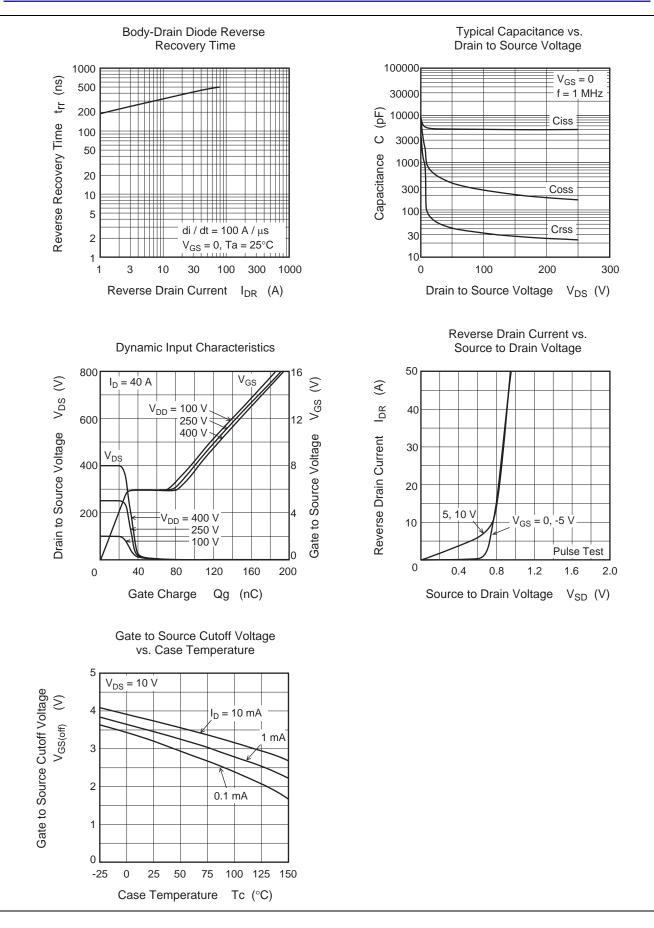
Notes: 4. Pulse test



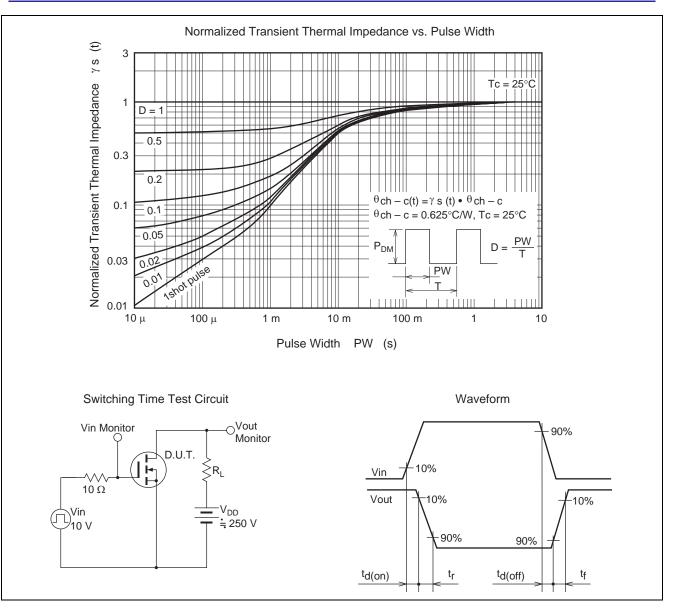
Main Characteristics





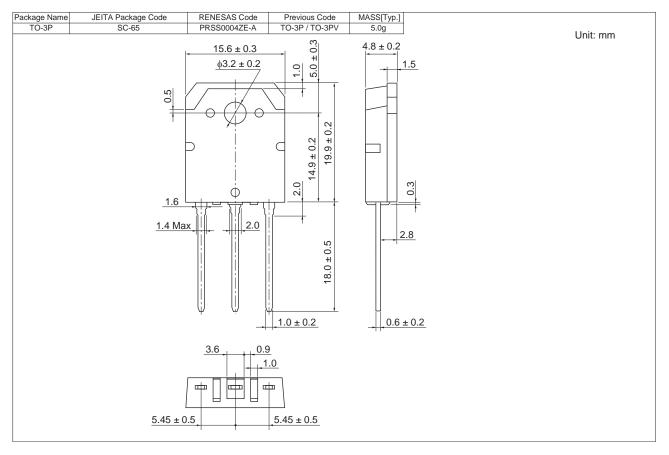








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK5020DPK-00-T0	360 pcs	Box (Tube)

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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